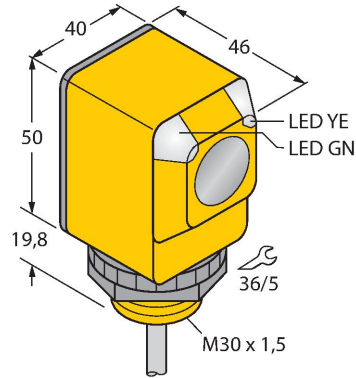


Q403E

Photoelectric Sensor – Opposed Mode Sensor (Emitter)



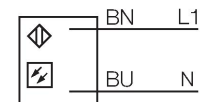
Technical data

Type	Q403E
ID	3032376
Optical data	
Function	Opposed mode sensor
Operating mode	Emitter
Light type	IR
Wavelength	950 nm
Range	0...60000 mm
Electrical data	
Operating voltage	20...250 VAC
Readiness delay	≤ 100 ms
Mechanical data	
Design	Rectangular, Q40
Dimensions	Ø 30 x 46 x 40.1 x 69.8 mm
Housing material	Plastic, Thermoplastic material
Lens	plastic, Polycarbonate
Electrical connection	Cable, 2 m, PVC
Number of cores	2
Core cross-section	0.5 mm ²
Ambient temperature	-40...+70 °C
Protection class	IP67
Special features	Encapsulated
Power-on indication	LED, Green
Excess gain indication	LED
Tests/approvals	
Approvals	CE, UL, CSA

Features

- Cable, 2 m
- Protection class IP67
- Ambient temperature: -40...+70 °C
- Operating voltage: 20...250 VAC

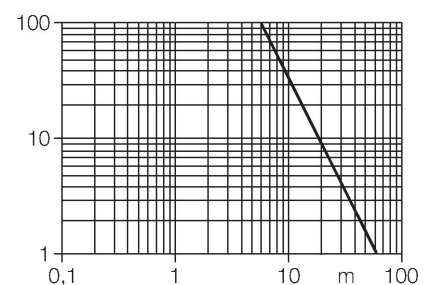
Wiring diagram



Functional principle

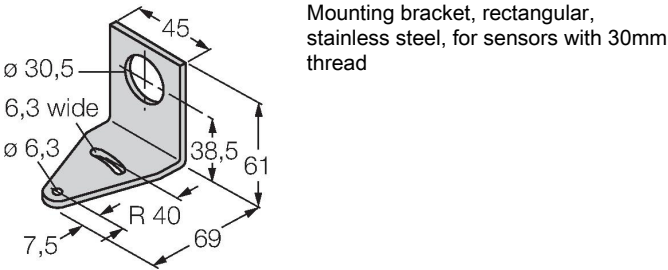
Opposed mode sensors consist of an emitter and receiver. They are installed opposite to each other so that the light from the emitter is aimed directly at the receiver. When an object interrupts or weakens the light beam, the sensor switches. Opposed mode sensors are the most reliable photoelectric sensors for detection of opaque targets. The excellent light/dark contrast and the high excess gain allow operation over larger distances and under difficult conditions.

Excess gain curve
Excess gain in relation to the distance

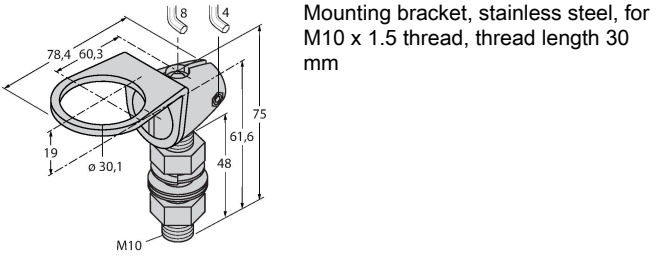


Accessories

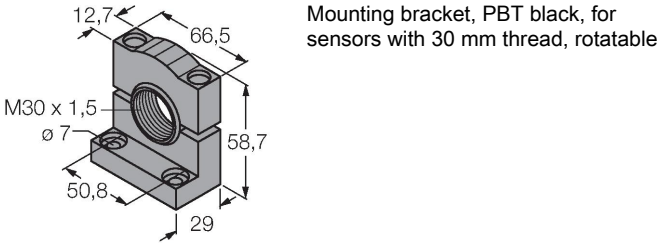
SMB30A 3032723



SMB30FAM10 3011185



SMB30SC 3052521



SMBAMS30P 3073135

